

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:	)	Confirmation No. 9762
Shinji MAEKAWA	)	
Serial No. 10/685,380	)	Examiner: David J. Goodwin
Filed: October 16, 2003	)	Group Art Unit: 2818
For: METHOD OF MANUFACTURING	)	
SEMICONDUCTOR DEVICE	)	Date: August 30, 2006

**INFORMATION DISCLOSURE STATEMENT**

**MAIL STOP AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicants hereby submit the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98.

The Commissioner is hereby authorized to charge the Deposit Account No. 19-2380 in the amount of \$180 to comply with the provisions of 37 C.F.R. § 1.97(c).

To assist the Examiner, the documents to be considered are listed on the attached form PTO-1449. The listed document by Kazuhiro Shimizu et al. was cited in a PTO Form 1449 filed in this application on October 16, 2003, and Applicants graciously acknowledge the supplemental paper mailed by the Examiner on August 23, 2006, enclosing a completed initialed copy of this PTO 1449. However, during a review of this form, Applicant noted that the publication year was not included in the previous citation of the Shimizu et al. article. The Examiner is again requested to consider this document, and so indicate by initialing the attached PTO Form 1449.

It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application, and that an Examiner-initialed a copy of this form be returned to the undersigned.

The Commissioner is hereby authorized to charge fees under 37 C.F.R. §§1.16, 1.17, 1.20(a), 1.20(b), 1.20(c), and 1.20(d) (except the Issue Fee) which may be required now or hereafter, or credit any overpayment to Deposit Account No. 19-2380. (740756-2660)

Respectfully submitted,

/John F. Guay, Reg.# 47248/

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Substitute for form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(use as many sheets as necessary)</i>			<b>Complete if Known</b>			
			Application Number		10/685,380	
			Filing Date		October 16, 2003	
			First Named Inventor		Shinji MAEKAWA	
			Art Unit		2818	
			Examiner Name		David Goodwin	
Sheet	1	of	1	Attorney Docket Number		740756-2660

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	U.S. Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code <sup>2</sup> (if known)			
		US-4,659,422	04/21/1987	Sakurai	
		US-6,322,625 B2	11/27/2001	Im	
		US-6,475,839 B2	11/05/2002	Zhang et al.	
		US-6,548,370 B1	04/15/2003	Kasahara et al.	
		US-6,599,788 B1	07/29/2003	Kawasaki et al.	
		US-6,730,550 B1	05/04/2004	Yamazaki et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>5</sup> (if known)				

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
		Kazuhiro SHIMIZU et al., "High-Mobility Poly-Si Thin-Film Transistors Fabricated by a Novel Excimer Laser Crystallization Method", IEEE TRANSACTIONS ON ELECTRON DEVICES., Vol. 40, No. 1, 1993, pp. 112-117.	

Examiner Signature		Date Considered	
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kinds Codes of USPTO Patent Documents at [www.uspto.gov](http://www.uspto.gov) or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> Applicant is to place a check mark here if English language Translation is attached.